











TMP708-Q1

SBOS828 - DECEMBER 2016

# TMP708-Q1 Automotive, Resistor-Programmable Temperature Switch in SOT Package

### **Features**

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level 3A
  - Device CDM ESD Classification Level C6
- Threshold Accuracy:
  - ±0.5°C Typical
  - ±3.5°C Maximum (60°C to 100°C)
- Temperature Threshold Set By 1% External Resistor
- Low Quiescent Current: 40 μA, Typical
- Open-Drain, Active-Low Output Stage
- Pin-Selectable 10°C or 30°C Hysteresis
- Reset Operation Specified at  $V_{CC} = 0.8 \text{ V}$
- Supply Range: 2.7 V to 5.5 V
- Package: 5-Pin SOT-23

# **Applications**

- Computers (Laptops and Desktops)
- Servers
- Industrial and Medical Equipment
- Storage Area Networks
- Automotive

# 3 Description

The TMP708-Q1 is a fully-integrated, resistorprogrammable temperature switch with a temperature threshold that is set by just one external resistor within the entire operating range. The TMP708-Q1 provides an open-drain, active-low output and has a 2.7-V to 5.5-V supply voltage range.

The temperature threshold accuracy is typically ±0.5°C, with a maximum of ±3.5°C (60°C to 100°C). The quiescent current consumption is typically 40 µA. Hysteresis is pin-selectable to 10°C or 30°C.

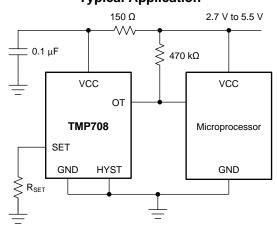
The TMP708-Q1 is available in a 5-pin, SOT-23 package.

### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)   |
|-------------|------------|-------------------|
| TMP708-Q1   | SOT-23 (5) | 2.90 mm x 1.60 mm |

(1) For all available packages, see the package option addendum at the end of the datasheet.

# **Typical Application**



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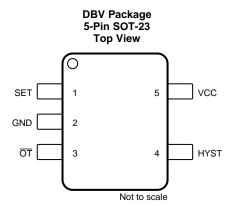
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# 4 Revision History

| DATE          | REVISION | NOTES            |  |  |
|---------------|----------|------------------|--|--|
| December 2016 | *        | Initial release. |  |  |

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# **5 Pin Configuration and Functions**



**Pin Functions** 

| PIN                |     | TYPE           | DESCRIPTION   |  |  |  |  |
|--------------------|-----|----------------|---|--|--|--|--|
| NAME               | NO. | ITPE           | DESCRIPTION   |  |  |  |  |
| GND                | 2   | Analog power   | Device ground   |  |  |  |  |
| HYST               | 4   | Digital input  | Hysteresis selection. For 10°C, HYST = VCC; for 30°C, HYST = GND.           |  |  |  |  |
| OT                 | 3   | Digital output | Open-drain, active low output   |  |  |  |  |
| SET                | 1   | Analog input   | Temperature set point. Connect an external 1% resistor between SET and GND. |  |  |  |  |
| VCC 5 Analog power |     | Analog power   | Power-supply voltage (2.7 V to 5.5 V)                                       |  |  |  |  |

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## 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

|             |                            | MIN  | MAX                   | UNIT |
|-------------|----------------------------|------|-----------------------|------|
|             | Supply, VCC                | -0.3 | 6                     |      |
| Voltage     | Input, SET and HYST        | -0.3 | V <sub>CC</sub> + 0.3 | V    |
|             | Output, OT                 | -0.3 | 6                     |      |
| Current     | Input                      |      | 20                    | A    |
|             | Output                     |      | 20                    | mA   |
| Temperature | Operating, T <sub>A</sub>  | -40  | 125                   |      |
|             | Junction, T <sub>J</sub>   |      | 150                   | °C   |
|             | Storatge, T <sub>stg</sub> | -65  | 150                   |      |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 6.2 ESD Ratings

|                    |                         |   | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| V <sub>(ESD)</sub> | Clastrostatia diasharas | Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup> | ±4000 | V    |
|                    | Electrostatic discharge | Charged-device model (CDM), per AEC Q100-011            | ±1000 | V    |

<sup>(1)</sup> AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                |                       | MIN | NOM MAX | UNIT |
|----------------|-----------------------|-----|---------|------|
| $V_{CC}$       | Supply voltage        | 2.7 | 5.5     | V    |
| T <sub>A</sub> | Operating temperature | 0   | 125     | °C   |

### 6.4 Thermal Information

|                      |  | TMP708-Q1    |      |
|----------------------|--|--------------|------|
|                      | THERMAL METRIC <sup>(1)</sup>                | DBV (SOT-23) | UNIT |
|                      |  | 5 PINS       |      |
| $R_{\theta JA}$      | Junction-to-ambient thermal resistance       | 217.9        | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance    | 86.3         | °C/W |
| $R_{\theta JB}$      | Junction-to-board thermal resistance         | 44.6         | °C/W |
| ΨЈТ                  | Junction-to-top characterization parameter   | 4.4          | °C/W |
| ΨЈВ                  | Junction-to-board characterization parameter | 43.8         | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A          | °C/W |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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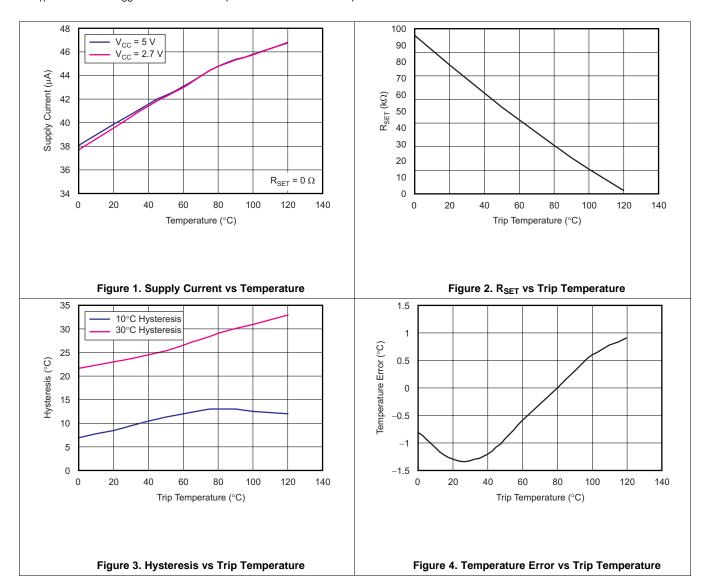
# 6.5 Electrical Characteristics

at  $T_A$  = 0°C to 125°C and  $V_{CC}$  = 2.7 V to 5.5 V (unless otherwise noted)

|                        | PARAMETER                | TEST CONDITIONS                | MIN                   | TYP  | MAX                   | UNIT |
|------------------------|--------------------------|--------------------------------|-----------------------|------|-----------------------|------|
| POWER S                | UPPLY                    | ,                              |                       |      |                       |      |
|                        | Committee accomment      | V <sub>CC</sub> = 5 V          |                       | 40   | 55                    | μA   |
| Icc                    | Supply current           | V <sub>CC</sub> = 2.7 V        |                       | 40   | 55                    | μA   |
| TEMPERA                | TURE                     |                                | ·                     |      |                       |      |
| T <sub>E</sub>         | Temperature error        | T <sub>A</sub> = 60°C to 100°C |                       | ±0.5 | ±3.5                  | °C   |
| DIGITAL I              | NPUT (HYST)              |                                | ·                     |      |                       |      |
| V <sub>IH</sub>        | High-level input voltage |                                | 0.7 × V <sub>CC</sub> |      |                       | V    |
| V <sub>IL</sub>        | Low-level input voltage  |                                |                       |      | 0.3 × V <sub>CC</sub> | V    |
| I <sub>lkg_in</sub>    | Input leakage current    |                                |                       | 1    |                       | μA   |
| C <sub>IN</sub>        | Input capacitance        |                                |                       | 10   |                       | pF   |
| ANALOG                 | INPUT (SET)              |                                |                       |      |                       |      |
| V <sub>IN</sub>        | Input voltage range      |                                | 0                     |      | V <sub>CC</sub>       | V    |
| DIGITAL O              | PEN-DRAIN OUTPUT (OT)    |                                |                       |      |                       |      |
| I <sub>(OT_SINK)</sub> | Output sink current      | V <sub>OT</sub> = 0.3 V        | 5                     | 12   |                       | mA   |
| I <sub>lkg(OT)</sub>   | Output leakage current   | $V_{OT} = V_{CC}$              |                       | 1    |                       | μA   |

# 6.6 Typical Characteristics

at  $T_A = 25$ °C and  $V_{CC} = 2.7$  V to 5.5 V (unless otherwise noted)





# 7 Detailed Description

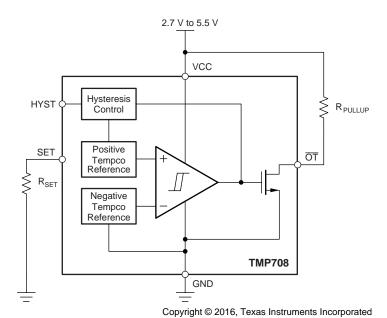
### 7.1 Overview

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The TMP708-Q1 is a fully-integrated, resistor-programmable temperature switch that incorporates two temperature-dependent voltage references and one comparator. One voltage reference exhibits a positive temperature coefficient (tempco), and the other voltage reference exhibits a negative tempco. The temperature at which both voltage references are equal determines the temperature trip point.

The Functional Block Diagram shows the comparator, the NFET open-drain device connected to the  $\overline{\text{OT}}$  pin, the positive tempco reference using the external R<sub>SET</sub> resistor, the negative tempco reference, and the hysteresis control. The voltage of the positive tempco reference is controlled by external resistor R<sub>SET</sub>.

## 7.2 Functional Block Diagram



Submit Documentation Feedback

### 7.3 Feature Description

### 7.3.1 Temperature Switch

The TMP708-Q1 temperature threshold is programmable from 0°C to 125°C and is set by an external 1% resistor from the SET pin to the GND pin. The TMP708-Q1 has an open-drain, active-low output structure that easily interfaces with a microprocessor.

The TMP708-Q1 reaches the temperature trip point when the voltage from the positive tempco reference exceeds the voltage from the negative tempco reference. This difference causes the output of the comparator to switch from logic 0 to logic 1. The comparator output drives the gate of the NFET open-drain device, and pulls the voltage on the  $\overline{OT}$  pin from logic 1 to logic 0 under these conditions; in other words, the output *trips*. Furthermore, the logic 1 output from the comparator causes the hysteresis control to increase the voltage of the positive tempco reference by an amount set by the logic setting on the HYST pin (10°C for logic 1 on the HYST pin; 30°C for logic 0 on the HYST pin). Increase the voltage of the positive tempco reference after the TMP708-Q1 trips to stop the TMP708-Q1 from untripping (voltage on the  $\overline{OT}$  pin changing from logic 0 to logic 1) until the local temperature reduces by the amount set by the HYST pin. After the local temperature reduces, and the voltage from the positive tempco reference is less than the voltage from the negative tempco reference, the output of the comparator switches from logic 1 to logic 0. This condition causes the voltage on the  $\overline{OT}$  pin to change from logic 0 to logic 1 (device untrips).

### 7.3.2 Hysteresis Input

The HYST pin is a digital input that allows the input hysteresis to be set at either 10°C (when HYST = VCC) or 30°C (when HYST = GND). The hysteresis function keeps the  $\overline{OT}$  pin from oscillating when the temperature is near the threshold. Thus, always connect the HYST pin to either VCC or GND. Other input voltages on this pin can cause abnormal supply currents or a device malfunction.

### 7.3.3 Set-Point Resistor (R<sub>SET</sub>)

Set the temperature threshold by connecting  $R_{SET}$  from the SET pin to GND. The value of  $R_{SET}$  is determined using either Figure 2 or Equation 1:

$$R_{SET}(k\Omega) = 0.0012T^2 - 0.9308T + 96.147$$

where

• T = temperature threshold in degrees Celsius.

(1)

#### 7.4 Device Functional Modes

The TMP708-Q1 device has a single functional mode. Normal operation for the TMP708-Q1 device occurs when the power-supply voltage applied across the VCC and GND pins is within the specified operating range of 2.7 V to 5.5 V.

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# 8 Application and Implementation

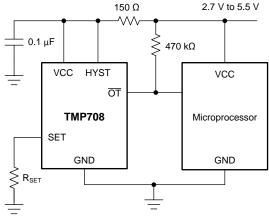
#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The TMP708-Q1 device is simple to configure. The only external components that the device requires are a bypass capacitor and pullup resistor. Power-supply bypassing is strongly recommended. Use a 0.1- $\mu$ F capacitor placed as close as possible to the VCC supply pin. To minimize the internal power dissipation of the TMP708-Q1 family of devices, use a pullup resistor value greater than 10 k $\Omega$  from the  $\overline{OT}$  pin to the VCC pin. See the *Hysteresis Input* section for hysteresis configuration, and the *Set-Point Resistor* ( $R_{SET}$ ) section for configuring the temperature threshold.

# 8.2 Typical Application



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Figure 5. Overtemperature Protection for a 60°C Trip Point

### 8.2.1 Design Requirements

For this design example, a 2.7-V to 5.5-V power supply, 60°C trip point, and 10°C hysteresis are used.

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### **Typical Application (continued)**

## 8.2.2 Detailed Design Procedure

Connect the HYST pin to VCC for 10°C hysteresis. For a 60°C temperature threshold, see the *Set-Point Resistor* ( $R_{SET}$ ) section to compute an ideal  $R_{SET}$  resistor value of 44.619 k $\Omega$ . Select the closest standard value resistor available; in this case, 44.2 k $\Omega$ . Use a 10-k $\Omega$  pullup resistor from the  $\overline{OT}$  pin to the VCC pin. To minimize power, a larger-value pullup resistor can be used, but must not exceed 470 k $\Omega$ . Place a 0.1- $\mu$ F bypass capacitor close to the TMP708-Q1 device in order to reduce noise coupled from the power supply.

# 8.2.3 Application Curves

Figure 6 shows an example of the hysteresis feature. The HYST pin is connected to VCC, so the TMP708-Q1 device is configured for 10°C of hysteresis. The device is configured for a 60°C trip temperature by the R<sub>SET</sub> resistor value; therefore, the OT output asserts low when the 60°C threshold is exceeded. The OT output remains asserted low until the sensor reaches 50°C.

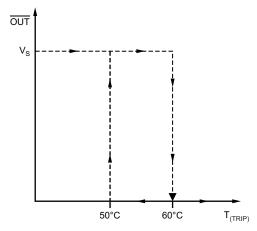


Figure 6. TMP708-Q1 Hysteresis Function

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9 Power Supply Recommendations

The TMP708-Q1 low supply current and supply range allow this device to be powered from many sources. Any significant noise on the VCC pin can result in a trip-point error. Minimize this noise by low-pass filtering the device supply ( $V_{CC}$ ) using a 150- $\Omega$  resistor and a 0.1- $\mu$ F capacitor.

## 10 Layout

### 10.1 Layout Guidelines

The TMP708-Q1 is extremely simple to lay out. Figure 7 shows the recommended board layout.

## 10.2 Layout Example

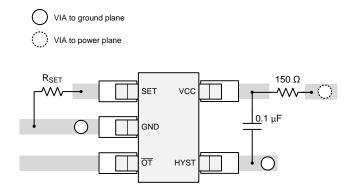


Figure 7. Recommended Layout

### 10.3 Thermal Considerations

The TMP708-Q1 quiescent current is typically 40  $\mu$ A. The device dissipates negligible power when the output drives a high-impedance load. Thus, the die temperature is the same as the package temperature. In order to maintain accurate temperature monitoring, provide a good thermal contact between the TMP708-Q1 package and the device being monitored. The rise in die temperature as a result of self-heating is given by Equation 2:

$$\Delta T_J = P_{DISS} \times \theta_{JA}$$

where

• P<sub>DISS</sub> = power dissipated by the device.

θ<sub>IA</sub> = package thermal resistance. Typical thermal resistance for SOT-23 package is 217.9°C/W.

To limit the effects of self-heating, keep the output current at a minimum level.

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# 11 Device and Documentation Support

### 11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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#### 11.3 Trademarks

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### 11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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### PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package   Pins   | Package qty   Carrier | RoHS | Lead finish/<br>Ball material | MSL rating/<br>Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|------------------|-----------------------|------|-------------------------------|----------------------------|--------------|------------------|
|                       |        |               |                  |                       |      | (4)                           | (5)                        |              |                  |
| TMP708AQDBVRQ1        | Active | Production    | SOT-23 (DBV)   5 | 3000   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 708Q             |
| TMP708AQDBVRQ1.B      | Active | Production    | SOT-23 (DBV)   5 | 3000   LARGE T&R      | Yes  | SN                            | Level-2-260C-1 YEAR        | -40 to 125   | 708Q             |

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF TMP708-Q1:

Catalog: TMP708

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



# **PACKAGE OPTION ADDENDUM**

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NOTE: Qualified Version Definitions:

 $_{\bullet}$  Catalog - TI's standard catalog product

# PACKAGE MATERIALS INFORMATION

www.ti.com 24-Apr-2020

# TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

| Device         | Package<br>Type | Package<br>Drawing |   |      | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TMP708AQDBVRQ1 | SOT-23          | DBV                | 5 | 3000 | 178.0                    | 9.0                      | 3.3        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |

# **PACKAGE MATERIALS INFORMATION**

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### \*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TMP708AQDBVRQ1 | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |



SMALL OUTLINE TRANSISTOR



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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